VS-400U(R) Series

Vishay Semiconductors



Standard Recovery Diodes (Stud Version), 400 A



| PRODUCT SUMMARY | | | | |
|------------------------------------|-----------------|--|--|--|
| I _{F(AV)} 400 A | | | | |
| Package | DO-205AB (DO-9) | | | |
| Circuit configuration Single diode | | | | |

FEATURES

- Wide current range
- · High surge current capabilities
- · Stud cathode and stud anode version
- Standard JEDEC[®] types
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-----------------------------------|-----------------|-------------|-------------------|--|--|
| PARAMETER | TEST CONDITIONS | VALUES | UNITS | | |
| | | 400 | A | | |
| I _{F(AV)} | T _C | 120 | °C | | |
| I _{F(RMS)} | | 630 | A | | |
| I _{FSM} | 50 Hz | 8250 | ٨ | | |
| | 60 Hz | 8640 | — A | | |
| l ² t | 50 Hz | 340 | kA ² s | | |
| 1-1 | 60 Hz | 311 | — ка²s | | |
| V _{RRM} | Range | 800 to 1600 | V | | |
| TJ | | -40 to 200 | °C | | |

ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | | | | |
|-----------------|-----------------|--|--|--|--|--|--|
| TYPE NUMBER | VOLTAGE CODE | V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA | | | |
| | 80 | 800 | 900 | | | | |
| VS-400U(R) 120 | | 1200 | 1300 | 15 | | | |
| | 160 | 1600 | 1700 | | | | |

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VS-400U(R) Series



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| FORWARD CONDUCTION | | | | | | | | |
|--|---------------------|--|-------------------------------------|--|--------|---------------------|-----|---|
| PARAMETER | SYMBOL | TEST CONDITIONS | | | VALUES | UNITS | | |
| Maximum average forward current | | | | 180° conduction, half sine wave | | | 400 | A |
| at case temperature | I _{F(AV)} | | ion, nan sine wa | ve | 120 | °C | | |
| Maximum RMS forward current | I _{F(RMS)} | DC at 110 °C | case temperatui | e | 630 | A | | |
| | | t = 10 ms | No voltage | | 8250 | A | | |
| Maximum peak, one cycle forward, | | t = 8.3 ms | reapplied | Sinusoidal half wave, initial T _J = T _J maximum | 8640 | | | |
| non-repetitive surge current | I _{FSM} | t = 10 ms | 100 % V _{BBM} | | 6940 | | | |
| | | t = 8.3 ms | reapplied | | 7270 | | | |
| Maximum I ² t for fusing | l ² t | t = 10 ms | No voltage reapplied | | 340 | - kA ² s | | |
| | | t = 8.3 ms | | | 311 | | | |
| | | t = 10 ms | 100 % V _{RRM} reapplied | | 241 | | | |
| | | t = 8.3 ms | | | 220 | | | |
| Maximum I ² \sqrt{t} for fusing | l²√t | t = 0.1 to 10 ms, no voltage reapplied | | | 3400 | kA²√s | | |
| Low level value of threshold voltage | V _{F(TO)1} | (16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum | | | 0.77 | v | | |
| High level value of threshold voltage | V _{F(TO)2} | $(I > \pi \times I_{F(AV)}), T_J = T_J maximum$ | | | 0.85 | v | | |
| Low level value of forward slope resistance | r _{f1} | (16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}),$ T_{J} = T_{J} maximum | | | 0.49 | mΩ | | |
| High level value of forward slope resistance | r _{f2} | $(I > \pi \times I_{F(AV)}), T_J = T_J maximum$ | | | 0.49 | 11152 | | |
| Maximum forward voltage drop | V _{FM} | I _{pk} = 1500 A, T | J = TJ maximum | , t _p = 10 ms sinusoidal wave | 1.62 | V | | |

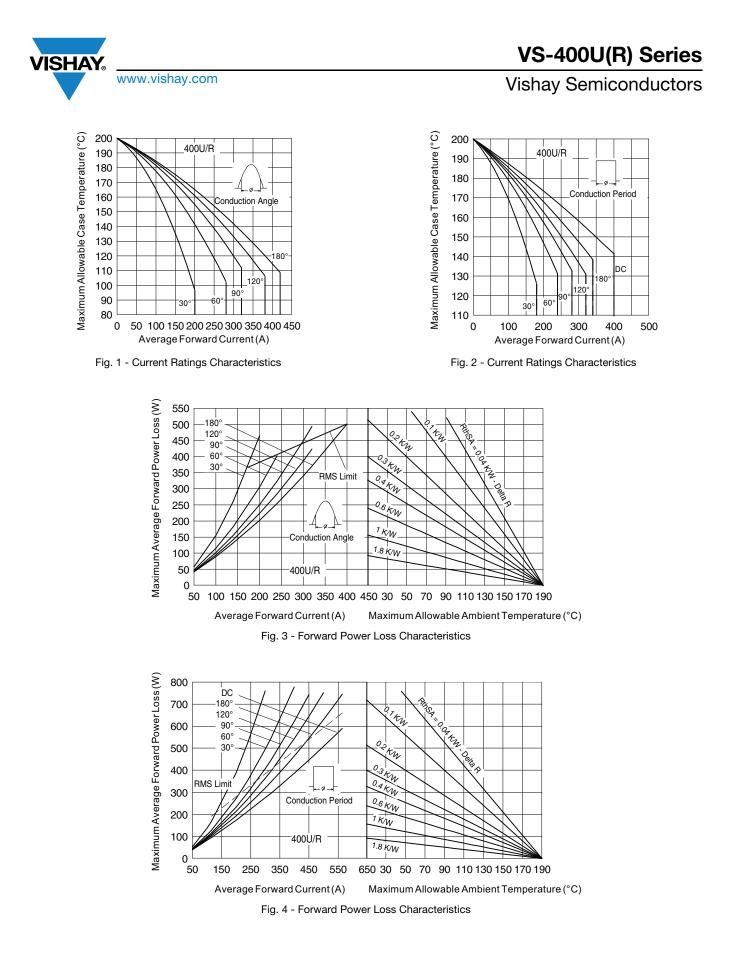
| THERMAL AND MECHANICAL SPECIFICATIONS | | | | |
|--|-----------------------------------|---|------------|----------|
| PARAMETER | SYMBOL | BOL TEST CONDITIONS | | UNITS |
| Maximum junction operating and storage temperature range | T _J , T _{Stg} | | -40 to 200 | °C |
| Maximum thermal resistance, junction to case | R _{thJC} | R _{thJC} DC operation | | K/W |
| Maximum thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth, flat and greased | | r./ vv |
| Maximum allowed mounting torque ± 10 % | | Not lubricated threads 27 | | N·m |
| Approximate weight | | | 250 | g |
| Case style | | See dimensions - link at the end of datasheet DO-205AB (DO-9) | | 3 (DO-9) |

| CONDUCTION ANGLE | SINUSOIDAL CONDUCTION | RECTANGULAR CONDUCTION | TEST CONDITIONS | UNITS | | |
|------------------|-----------------------|------------------------|---------------------|-------|--|--|
| 180° | 0.020 | 0.013 | | | | |
| 120° | 0.023 | 0.023 | | | | |
| 90° | 0.029 | 0.031 | $T_J = T_J maximum$ | K/W | | |
| 60° | 0.042 | 0.044 | | | | |
| 30° | 0.073 | 0.074 | | | | |

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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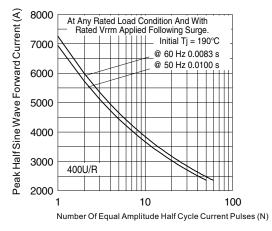


Fig. 5 - Maximum Non-Repetitive Surge Current

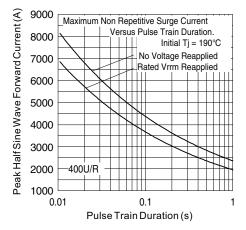


Fig. 6 - Maximum Non-Repetitive Surge Current

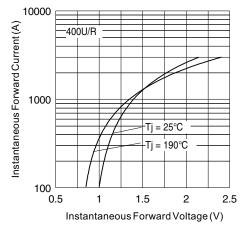
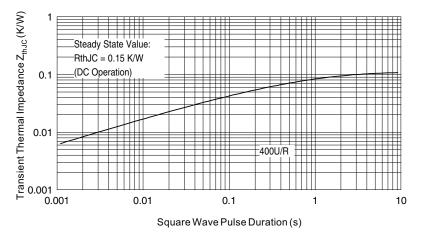


Fig. 7 - Forward Voltage Drop Characteristics





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ORDERING INFORMATION TABLE

| Device code | vs- | 40 | 0 | U | R | 160 | D | |
|-------------|--|--------|----------|----------|----------------------|------------|----------|---------------|
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | |
| | 1 - | · Vish | iay Sem | iconduc | tors pro | duct | | |
| | 2 - 40 = Essential part number | | | | | | | |
| | 3 - | 0 = 3 | Standar | d recove | ery devi | ce | | |
| | 4 - U = Stud normal polarity (cathode to stud) | | | | | | | |
| | 5 - | • No | one = St | ud norm | nal pola | rity (cath | node to | stud) |
| | | • R | = Stud r | everse | polarity | (anode | to stud) | |
| | 6 - | Volt | age cod | e x 10 = | · V _{RRM} (| see Vol | tage Ra | atings table) |
| | 7 - | Diffu | used dio | de | | | | |

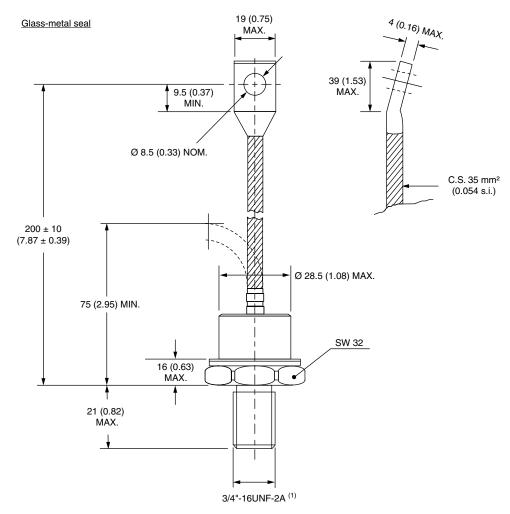
| LINKS TO RELATED DOCUMENTS | | | | |
|----------------------------|--------------------------|--|--|--|
| Dimensions | www.vishay.com/doc?95339 | | | |

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DO-205AB (DO-9) for 400U(R) Series

DIMENSIONS in millimeters (inches)



Note

• For metric device: M16 x 1.5 contact factory



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